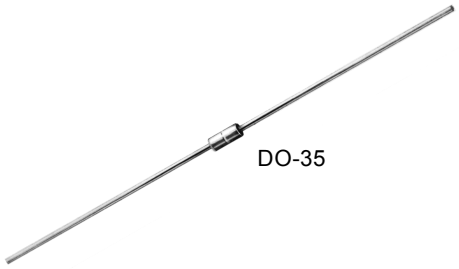
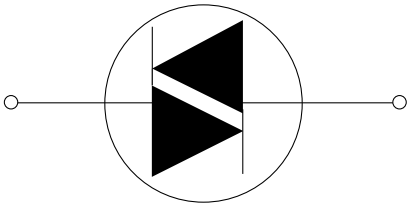
8



DO-35

DO-214AA



Bilateral Trigger Diacs

HT and ST Series

General Description

Teccor's "HT" and "ST" Series of bilateral trigger diacs offers a range of voltage characteristics from 27 to 70 volts.

The diac semiconductor is a full-wave or bidirectional thyristor. It is triggered from a blocking-to-conduction state for either polarity of applied voltage whenever the amplitude of applied voltage exceeds the breakover voltage rating of the diac.

The Teccor line of diacs features glass-passivated junctions to ensure long term device reliability and parameter stability. Teccor's glass offers a rugged, reliable barrier against junction contamination.

The diac specifications listed in this data sheet are for standard products. Special parameter selections such as close tolerance voltage symmetry are available. Please consult the factory for more information for custom design applications. Suffix RP signifies tape-and-reel packing. Example: HT32RP.

Features

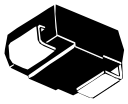
- **Glass passivated junctions**
- **Wide voltage range selections**

"ST" Series

- **Epoxy SMT package**
- **High temperature solder bonded die attachment**

"HT" Series

- **DO-35 trigger package**
- **Pre-tinned leads**

ELECTRICAL CHARACTERISTICS T_C = 25°C							
Part No.		V_{BO}		ΔV_{BO}	V_{BB}	I_{BO}	I_{TRM}
 DO-35	 DO-214AA	Breakover Voltage (Forward and Reverse) Volts		Breakover Voltage Symmetry ΔV_{BO} = $[\,\lvert +V_{BO}\rvert - \lvert -V_{BO}\rvert\,]$ Volts	Dynamic Breakback Voltage (3) $\lvert \Delta V\pm \rvert$ Volts	Peak Breakover Current at Breakover Voltage µAmps	Peak Pulse Current for 10µs 120 PPS $T_A \leq 40°C$ Amps
		MIN	MAX	MAX	MIN	MAX	MAX
HT-32		**27**	**37**	**3 (1)**	**10 (2)**	**25**	**2.0**
HT-32A / HT-5761		**28**	**36**	**2 (1)**	**7 at 10mA (4)**	**25**	**2.0**
HT-32B / HT-5761A		**30**	**34**	**2 (1)**	**7 at 10mA (4)**	**25**	**2.0**
HT-34B	**ST-34B**	**32**	**36**	**2 (1)**	**10 (2)**	**25**	**2.0**
HT-35	**ST-35**	**30**	**40**	**3 (1)**	**10 (2)**	**25**	**2.0**
HT-36A / HT-5762	**ST-36A**	**32**	**40**	**2 (1)**	**7 at 10mA (4)**	**25**	**2.0**
HT-36B	**ST-36B**	**34**	**38**	**2 (1)**	**10 (2)**	**25**	**2.0**
HT-40	**ST-40**	**35**	**45**	**3 (1)**	**10 (2)**	**25**	**2.0**
HT-60		**56**	**70**	**4**	**20 (2)**	**25**	**1.5**

General Notes

- Lead solder temperature is +230°C max. for 10 seconds max.; ≥ 1/16" (1.59mm) from case.
- See “Package Dimensions” section of this catalog.

Electrical Specification Notes

(1) Breakover Voltage symmetry as close as 1.0V is available from factory on these products.

(2) See Figures 8.4 and 8.5 for Test Circuit and waveforms.

(3) Typical switching time is 900 nano-seconds measured at I_{PK} (see Figure 8.4) across a 20Ω resistor (see Figure 8.5). Switching time defined as rise time of I_{PK} between the 10% to 90% points.

(4) See Figure 8.7.

Bilateral Trigger DIAC Specifications

- Maximum Ratings, Absolute-Maximum Values

  Maximum Trigger Firing Capacitance: 0.1µF
  Device Dissipation (at T_A = -40° to +40°C): 250mW for DO-35 and 300mW for DO-214AA
  Derate Above +40°C: 3.6mW/°C for DO-35 and 3mW/°C for DO-214AA

- Temperature Ranges

  Storage: -40°C to +125°C
  Operating (Junction): -40°C to +125°C

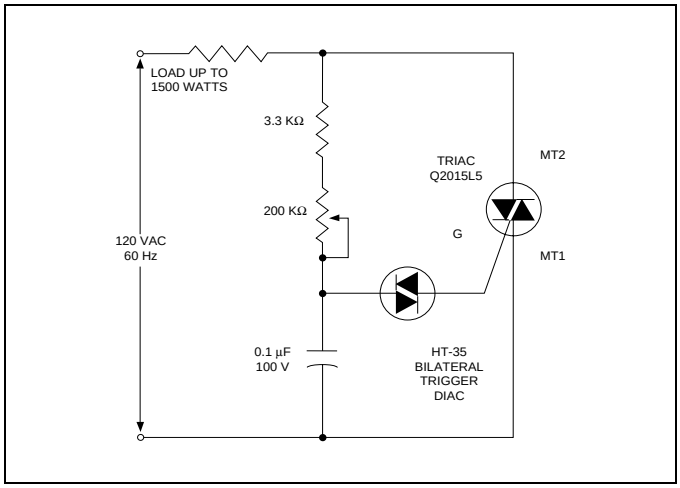
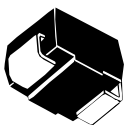


Figure 8.1 Typical Diac-Triac Full-Wave Phase Control Circuit using Lower Voltage Diacs

HT and ST Series Thermal Resistance **Junction to Lead - $R_{\theta JL}$: °C/W** **Junction to Ambient [$R_{\theta JA}$]: °C/W** **(based on maximum lead temperature of 90°C for DO-214AA and 85°C for DO-35 devices)**	
Y	S
	
DO-35	DO-214AA
100 [278] °C/W	65 [200] °C/W

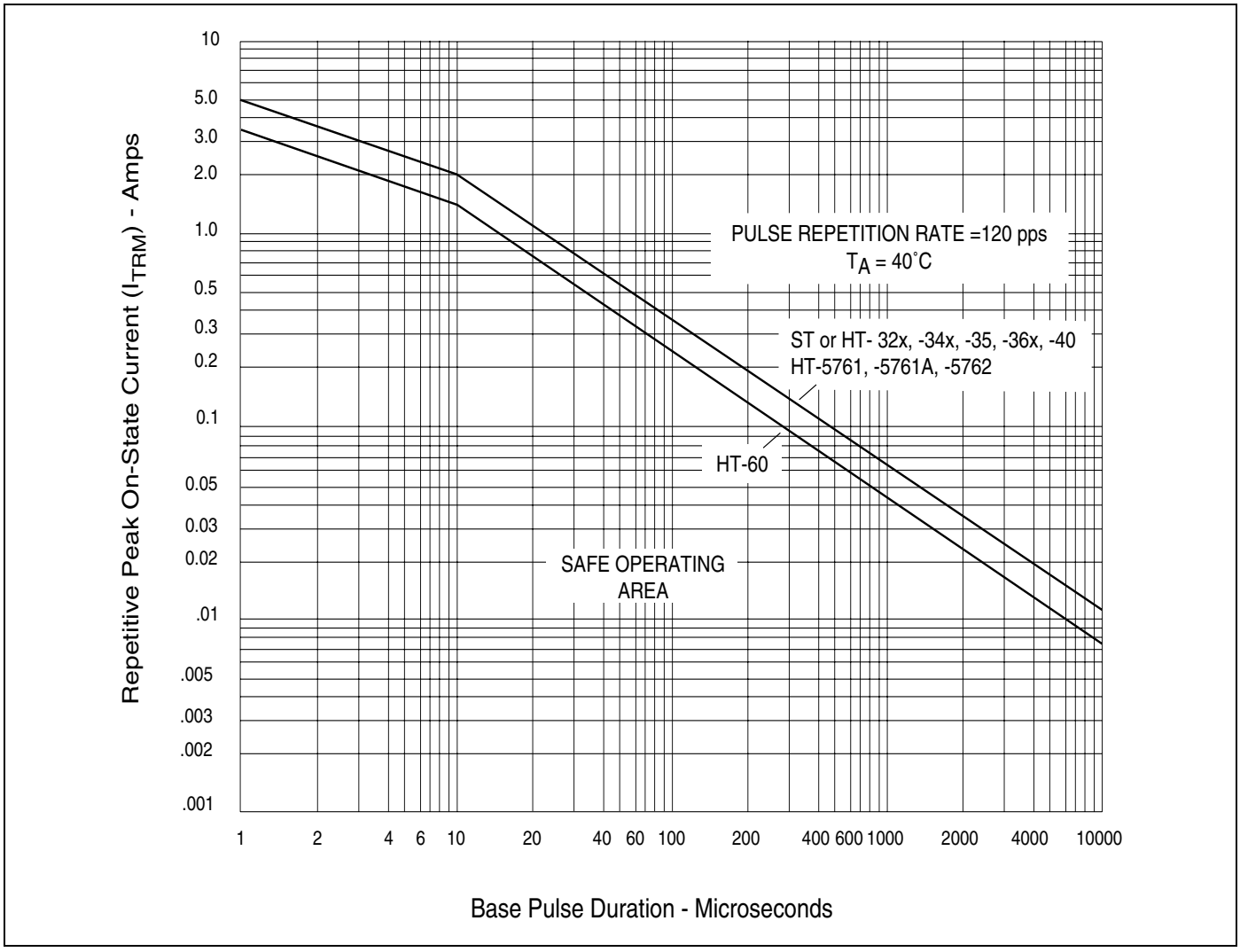


Figure 8.2 Repetitive Peak On-State Current vs Pulse Duration

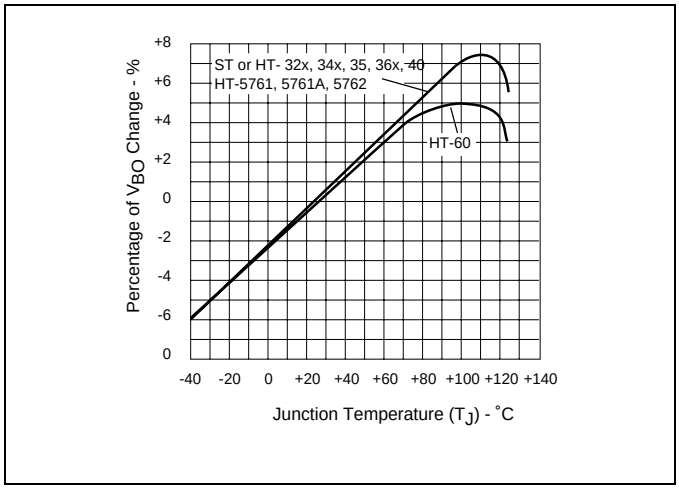


Figure 8.3 Normalized V_{BO} Change vs Junction Temperature

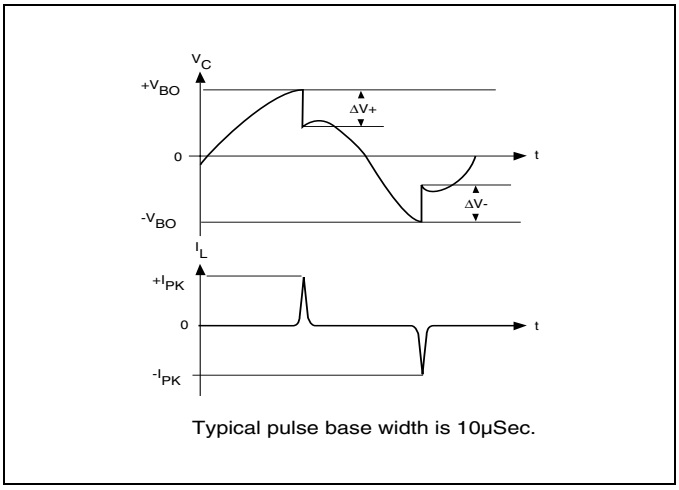


Figure 8.4 Test Circuit Waveforms (See Figure 8.5.)

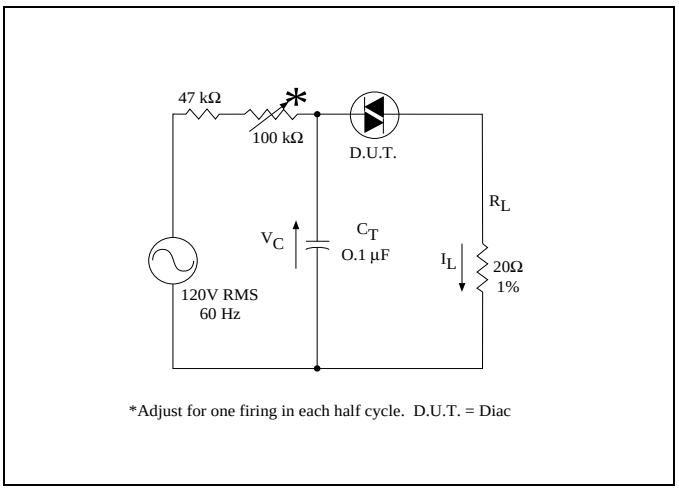


Figure 8.5 Circuit Used to Measure Diac Characteristics (See Figure 8.4.)

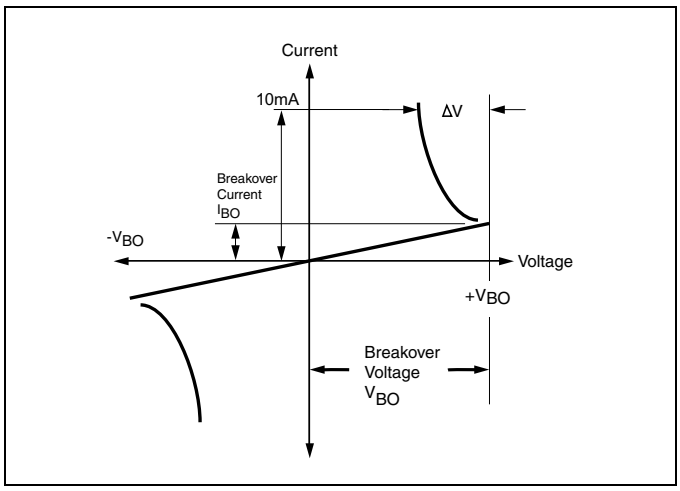


Figure 8.7 V-I Characteristics

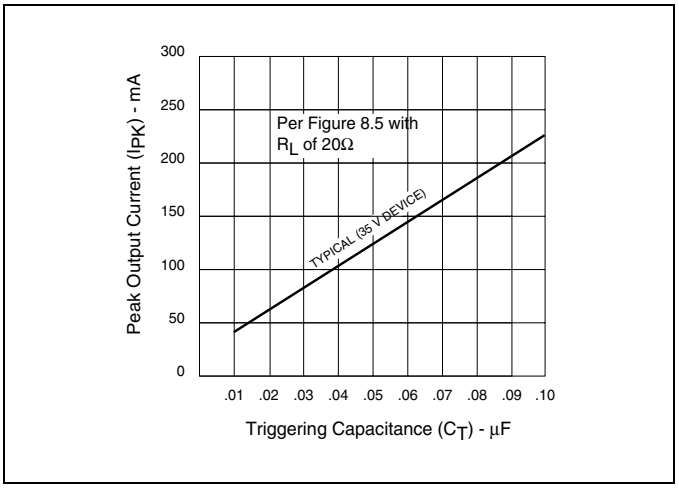


Figure 8.6 Peak Output Current vs Triggering Capacitance